



Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 40 to 100 V

Forward Current - 3 A

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMC
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.22g / 0.0077oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View

Marking Code: SS32 ~ SS320

Simplified outline SMC and symbol

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	SS32C	SS34C	SS36C	SS38C	SS310C	SS312C	SS315C	SS320C	Units					
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V					
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V					
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V					
Maximum Average Forward Rectified Current	$I_{F(AV)}$	3.0							A						
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	80							A						
Max Instantaneous Forward Voltage at 3 A	V_F	0.55		0.70		0.85		0.95		V					
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	I_R	0.5		5		0.3		3		mA					
Typical Junction Capacitance ⁽¹⁾	C_j	450			350			pF							
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	50							°C/W						
Operating Junction Temperature Range	T_j	-55 ~ +125							°C						
Storage Temperature Range	T_{stg}	-55 ~ +150							°C						

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

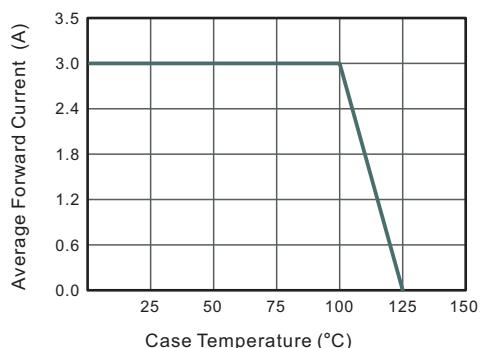


Fig.2 Typical Reverse Characteristics

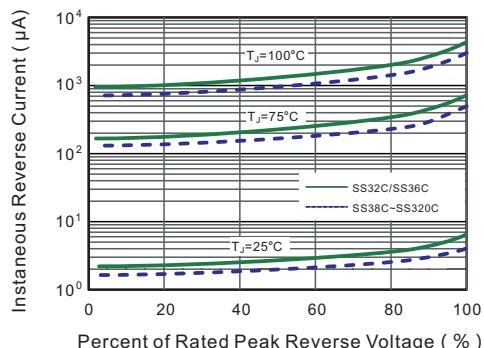


Fig.3 Typical Forward Characteristic

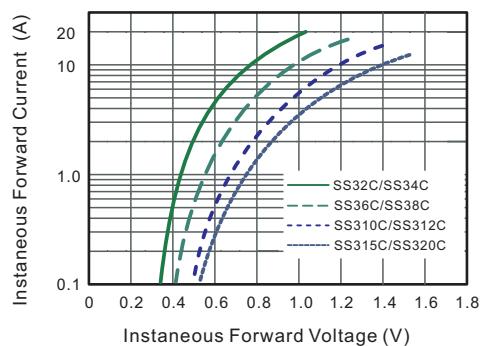


Fig.4 Typical Junction Capacitance

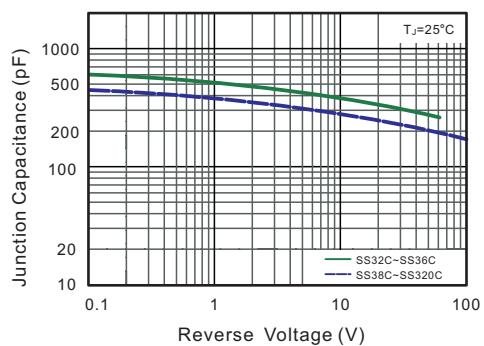


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

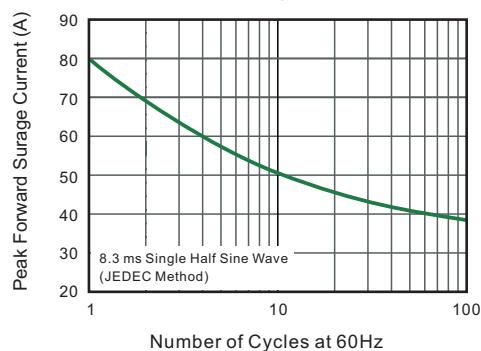
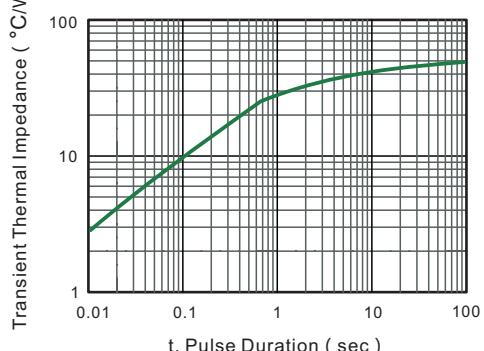


Fig.6- Typical Transient Thermal Impedance

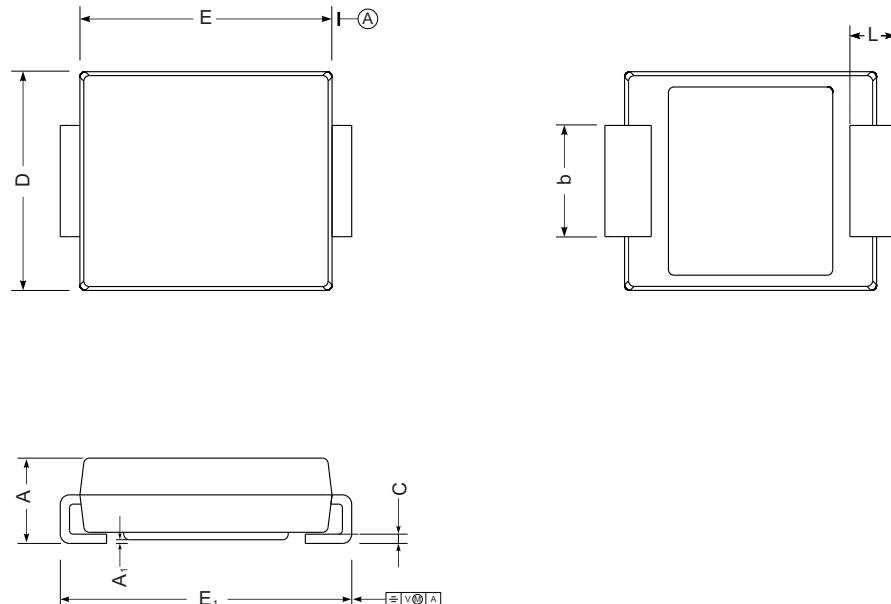




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

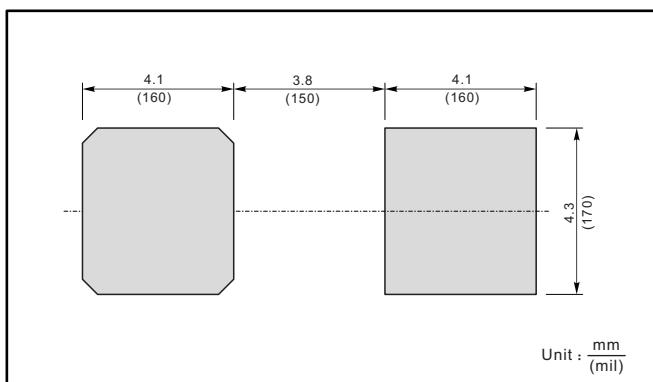
SMC



SMC mechanical data

UNIT		A	E	D	E ₁	A ₁	C	L	b
mm	max	2.62	7.0	6.2	8.0	0.21	0.31	1.6	3.25
	min	2.00	6.5	5.6	7.6	0.05	0.15	0.9	2.75
mil	max	103	276	244	315	8.3	12	63	128
	min	79	256	220	299	2.0	5.9	35	108

The recommended mounting pad size



Marking

Type number	Marking code
SS32C	SS32
SS34C	SS34
SS36C	SS36
SS38C	SS38
SS310C	SS310
SS312C	SS312
SS315C	SS315
SS320C	SS320

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